









	<h2>H11A817SD</h2>
	<p>Hersteller-Teilenummer: H11A817SD</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: OPTOISO 5.3KV TRANSISTOR 4SMD</p> <p>Datenblätter:  H11A817SD.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 20000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	H11A817SD
Hersteller	Fairchild/ON Semiconductor
Beschreibung	OPTOISO 5.3KV TRANSISTOR 4SMD
Kategorie	Isolatoren > Optoisolatoren - Transistor, Photovoltaik-
Teilstatus	20000 pcs Stock
Serie	-
Eingabetyp	DC
Betriebstemperatur	-55°C ~ 100°C
Befestigungsart	Surface Mount
Ausgabebetyp	Transistor
Anzahl der Kanäle	1
Verpackung / Gehäuse	4-SMD, Gull Wing
Supplier Device-Gehäuse	4-SMD
Strom - Ausgang / Kanal	50mA
Spannung - Isolation	5300Vrms
Aufstieg / Fallzeit (Typ)	2.4µs, 2.4µs
Spannung - Ausgabe (max)	70V
Spannung - Vorwärts (Vf) (Typ)	1.2V
Strom - DC Vorwärts (If) (Max)	50mA
Gleichstrom-Übertragungsverhältnis (min)	50% @ 5mA
Stromübertragungsverhältnis (max)	600% @ 5mA
Ein- / Ausschaltzeit (Typ)	-
VCE Sättigung (max)	200mV
Verpackung	Tape & Reel (TR)





























H11A817SD ist neu im Original, Suche H11A817SD Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie H11A817SD Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage H11A817SD: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>H11A817S Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817SD AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817DSD////////// FSC H11A817DSD////////// FSC</p>	 <p>H11A817W Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>
 <p>H11A817DW AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>	 <p>H11A817X-5627W FSC H11A817X-5627W FSC</p>	 <p>H11A817W AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>	 <p>H11A817X FAIRCHILD H11A817X FAIRCHILD</p>

heiße Teile

Mehr

 H11A817A3SD	 H11A817ASD	 H11A817ASD	D H11A817B	 H11A817B
 H11A817B.3SD	 H11A817B300	D H11A817B300	 H11A817B3SD	 H11A817B3SD
 H11A817BSD	 H11A817BSD	 H11A817BW	 H11A817BW	 H11A817C
D H11A817C	 H11A817C300	 H11A817C300	 H11A817C3SD	 H11A817C3SD
 H11A817CSD	 H11A817CSD	 H11A817CW	 H11A817CW	 H11A817SD
 H11A817X	 H11A817X-5627W	D H11A817X-5632	 H11AA1-X007T	 H11AA1-X007T
 H11AA1SR2M	D H11AA1SR2M	 H11AA1TM	 H11AA1TM	 H11AA1TVM
 H11AA1TVM	 H11AA2SM	 H11AA2SM	 H11AA2SR2M	 H11AA2SR2M
 H11AA2VM	 H11AA2VM	 H11AA3SD	D H11AA3SD	 H11AA3SM
 H11AA3SM	 H11AA3SR2M	 H11AA3SR2M	 H11AA3SR2VM	 H11AA3SR2VM

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